

# Phonon-mediated Quantum Capacitance Detectors for astroparticle applications

**Karthik Ramanathan**

Caltech: Sunil Golwala

JPL: Pierre Echternach

Weizmann Institute: Serge Rosenblum

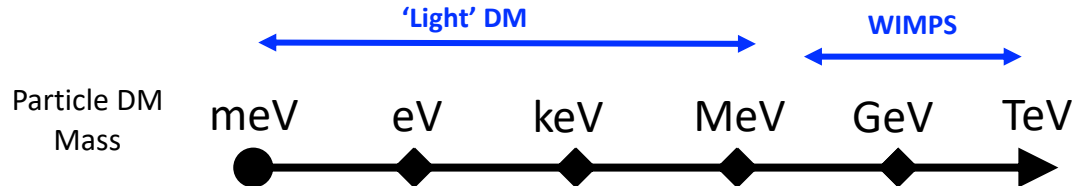
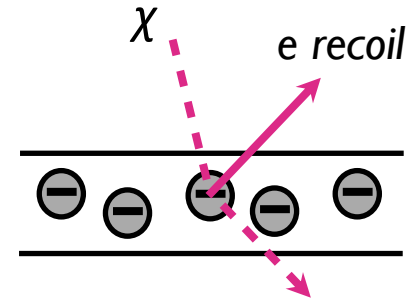
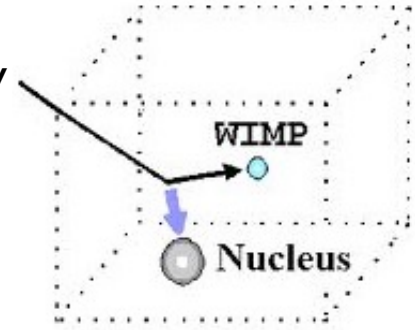
SLAC: Noah Kurinsky



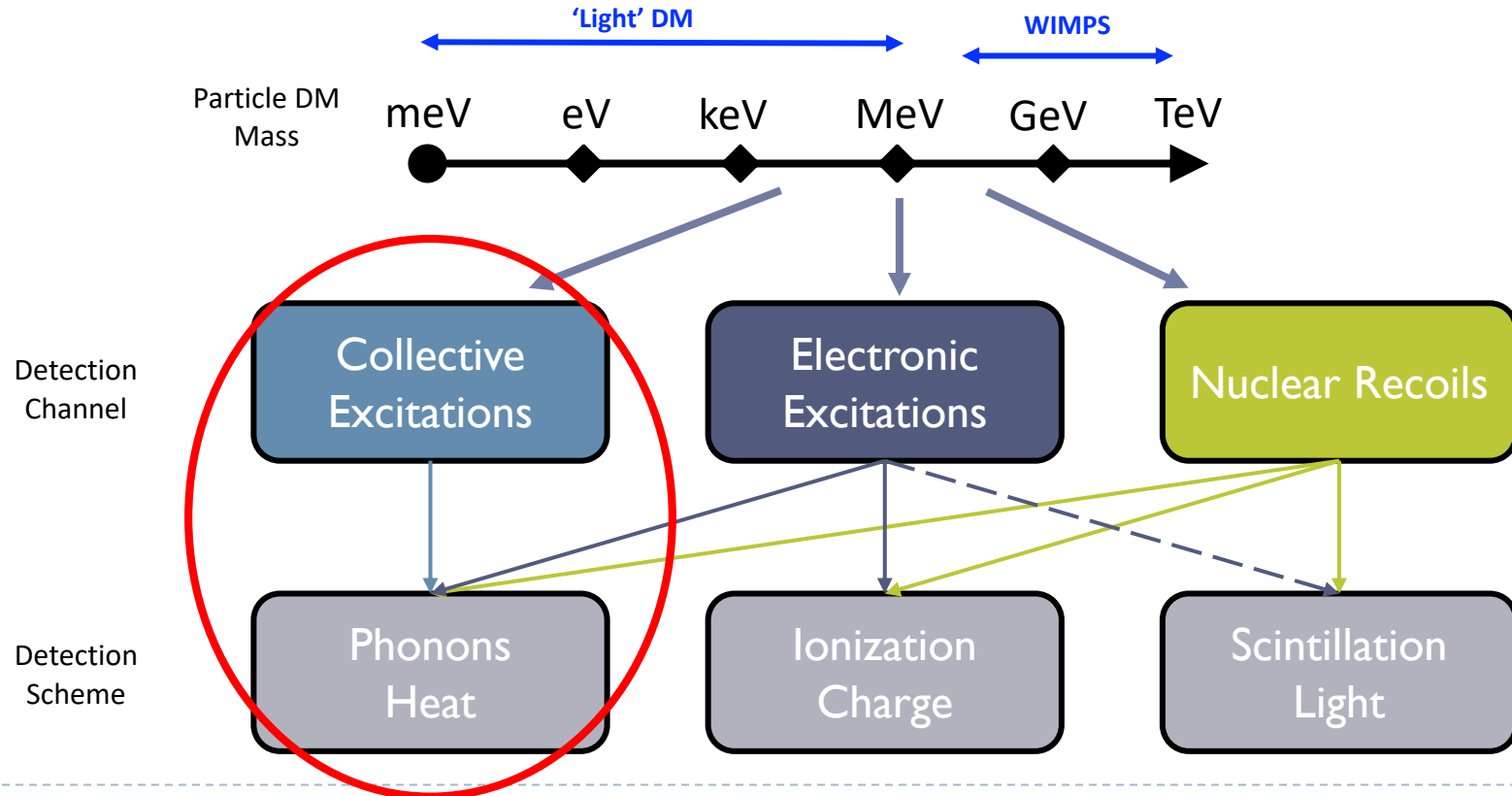
CPAD 2022 Stony Brook

# Dark Matter

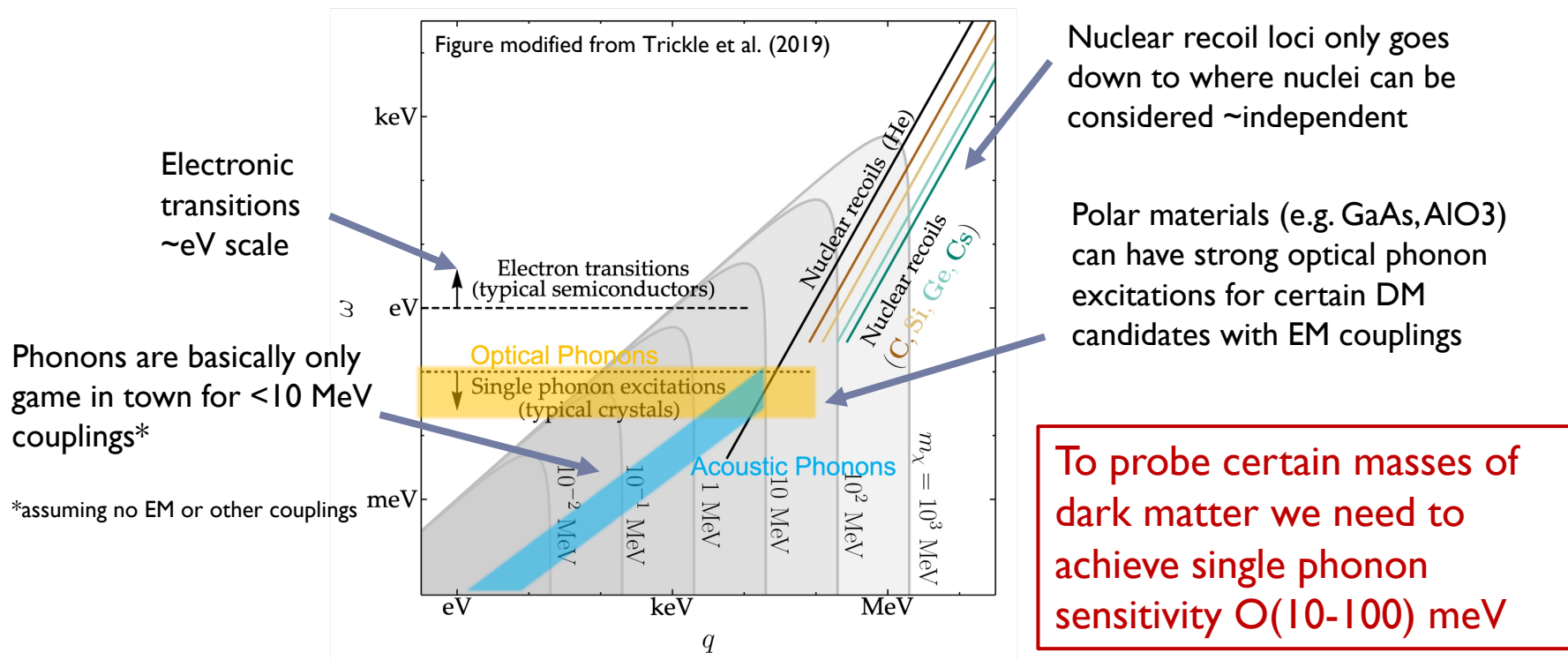
- ▶ Strong cosmological and astrophysical evidence for some missing matter in the universe comprising  $\sim 25\%$  of the total mass-energy of the Universe.
- ▶ Assuming **Particle Dark Matter**, whole zoo of models:
  - ▶ Perhaps detectable by **DM-nucleus** scattering or **DM-electron** processes but name of the game is **build a very sensitive detector and wait for clean signals from interactions**
- ▶ Energy deposited in a detector model dependent, but generally scales with mass  $\rightarrow O(100)$  MeV  $c^{-2}$  nuclear recoils gets you only  $O(eV)$  deposits in Si ☹



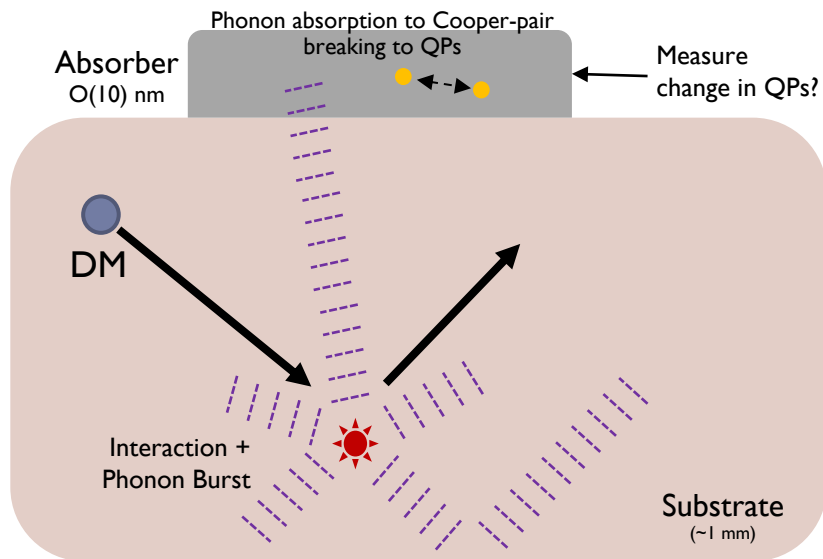
# Detection Channels



# Kinematic Space



# The (athermal) Phonon Channel



1. Point like fireball of  $O(\text{THz})$  phonons at interaction
2. Decay into lower energy phonons
3. Quasi-diffuse propagation  $\rightarrow$  athermal and “ballistic”
4. Phonons encountering e.g. superconducting metallic interface can be absorbed
5. Break Cooper-pairs  $\rightarrow$  QPs  $\rightarrow$  subsequent cascades

+ Phonon energies  $O(\text{meV})$

+ Preserves info about interaction position and energy

+ Many thousands of attempts to be absorbed by the detector

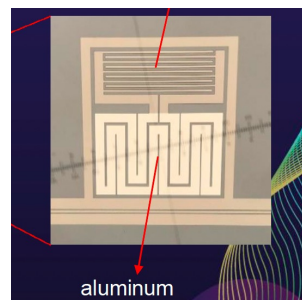
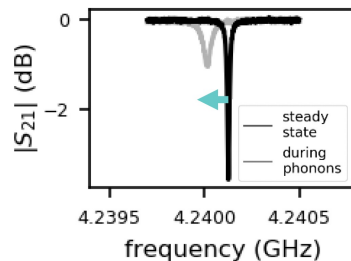
+ No relevant fluctuation background, since thermal phonon bath suppressed by mK cryogenic operation

- Diffusive nature means phonon energy can be split across multiple sensors

## Kinetic Inductance Detectors (KIDs)

- Superconductors have an AC inductance due to physical inertia of Cooper pairs → **Kinetic Inductance**

Design Stage	$\sigma_{pt}$ Ig Si absorber
<b>Current Technique</b>	<b>10-20 eV (meas.)</b>
<b>Optimized Single KID</b>	<b>5 eV (proj.) - 2023</b>
<b>Quantum Limited Amplifier</b>	<b>1 eV (proj.) - 2023</b>
<b>Improve <math>t_{qp}</math> to 1 ms</b>	<b>0.5 eV (est.) - 2024</b>
<b>Lower <math>T_c</math> material</b>	<b>O(100) meV (est.) 2025+</b>



- + Highly multiplexable, kHz linewidths on GHz readout
- + Fundamentally non-dissipative
- High residual quasiparticle level  $\sim 10$ -1000  $\mu\text{m}^{-3}$  of unknown origin, suspected to be readout power generated → limits quasiparticle lifetime and worsens sensitivity and resolution.

## Transition Edge Sensors (TESs)

- Voltage biased to sit at superconducting transition

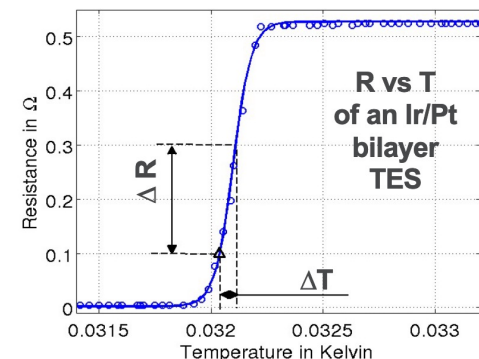
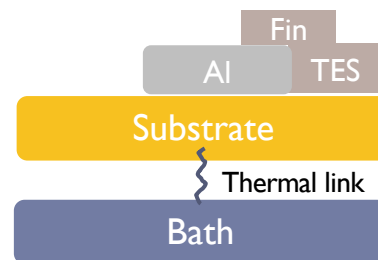


Figure from Chang, Wang Snowmass 2021 talk (2022)

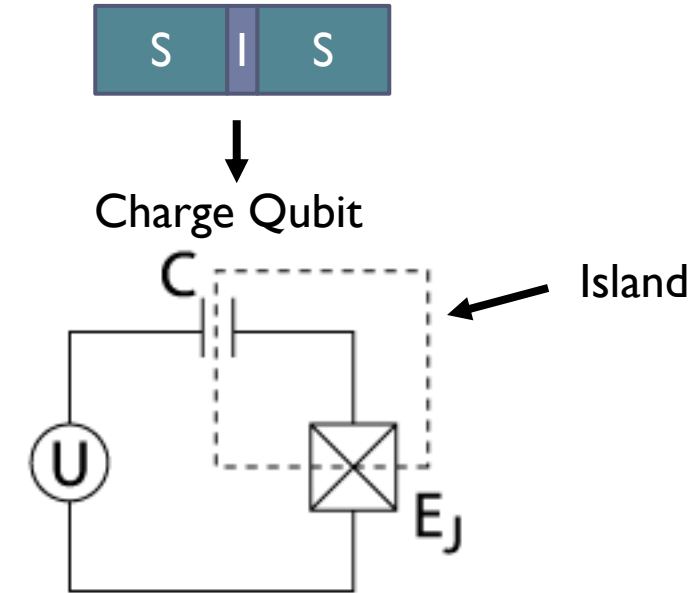
- + 30 year history of development with validated noise modelling
- Need low  $T_c$  → 10 mK to improve performance - challenging materials + deposition/fabrication R&D
- $T_c^{3/2}$  & thermal conductance  $\sim T^4$  still valid?

Demonstrated down to 2.26 eV baseline resolution on gm-scale absorber

# Qubits

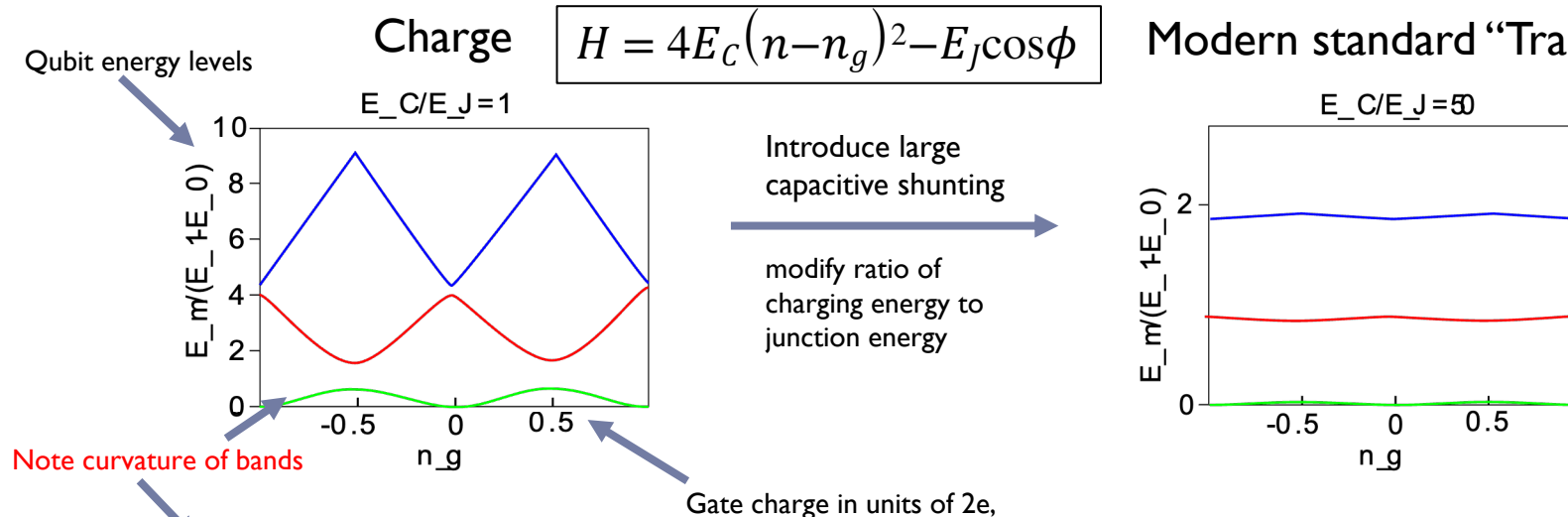
- Two-level systems  $|0\rangle, |1\rangle$
- Building block of quantum computers. Heralded as the future of computing etc. etc.
- Superconducting materials are one scheme in realizing qubits (opposed to photonics, trapped atoms etc.)
- Early implementation: **Charge Qubit / Cooper-Pair Box**
  - Well defined charge states  $\rightarrow$  presence or absence of Cooper pairs on the Island.
  - *However very sensitive to charge noise (quasiparticle poisoning), coherence times of only a few us*

Superconducting Tunnel Junctions/Josephson Junctions



## Charge $\leftrightarrow$ Transmon Regime

Figures from Wikipedia, Transmon Qubit (2022)



$$C_i = -\frac{C_g^2}{e^2} \frac{\partial^2 E_i}{\partial n_g^2}$$

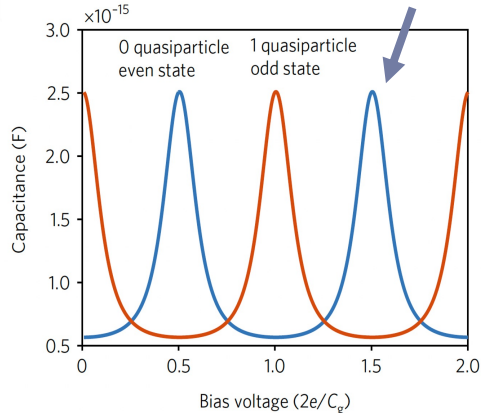
Can interpret the curvature as a capacitive term  $\rightarrow$  changes every time a quasiparticle tunnels over. **Couple to a resonator and see change of resonant frequency**

$$\delta C|_{n_g=1/2}^{n_g=0} = \frac{C_g^2}{C_\Sigma} \frac{4E_C}{E_J} \left( 1 - \left[ 1 + \left( \frac{E_C}{E_J} \right)^2 \right]^{-\frac{3}{2}} \right) \approx \frac{C_g^2}{C_\Sigma} \frac{4E_C}{E_J} \quad \text{O(MHz)}$$

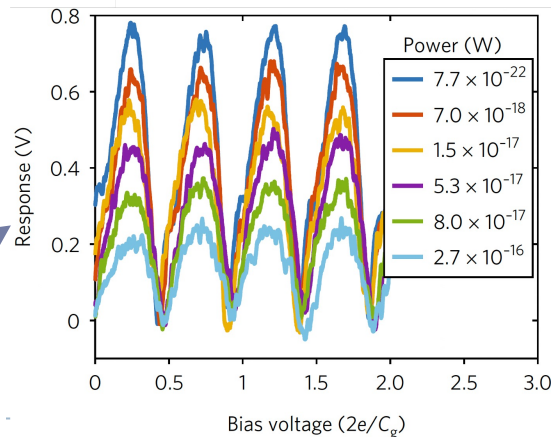
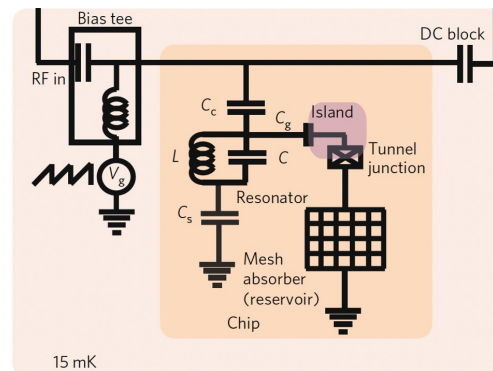


# Quantum Capacitance Detectors

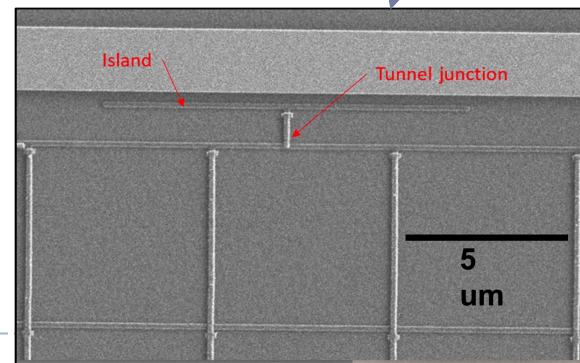
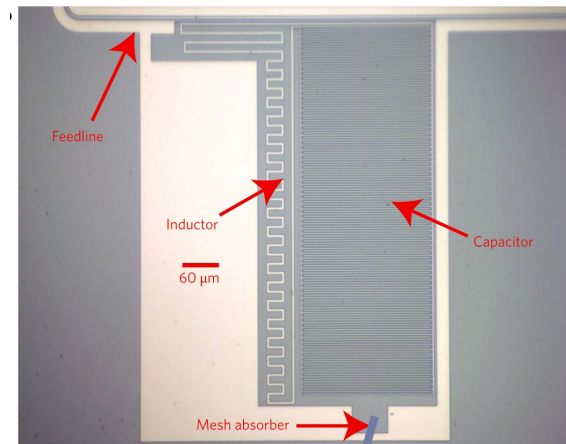
- Couple the circuit to an **absorber** and **resonator** and **make a detector!**
- Even-odd island QP occupancy  $\rightarrow$  Relate the tunneling rate to the number of quasiparticles produced in an absorber element.



Lots of potential for astronomical operation at low photon bkg. shot noise.



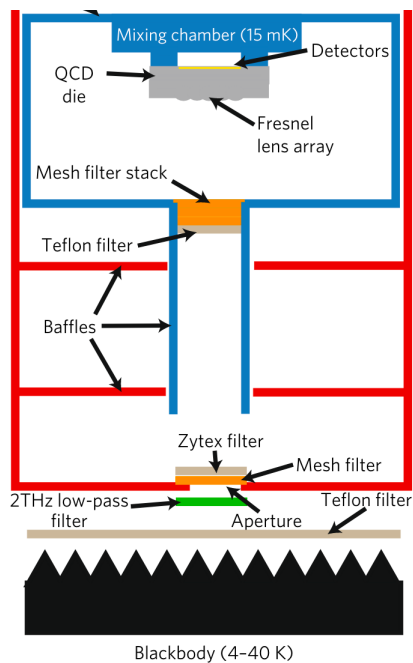
Echternach et al, Nature Astronomy, 2017



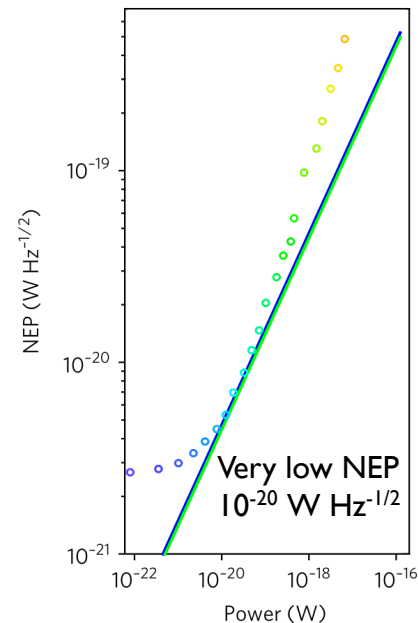
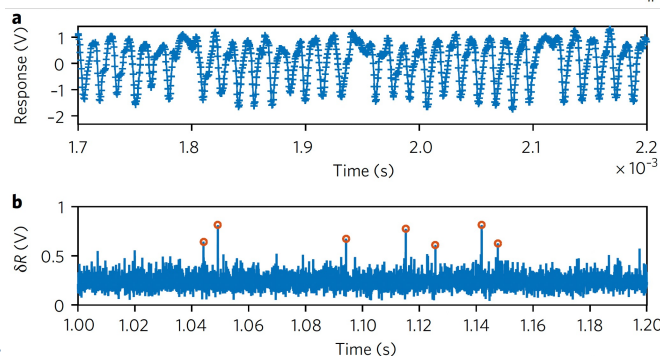
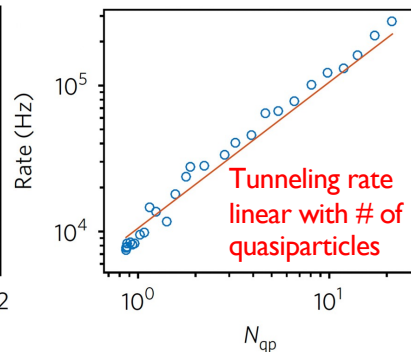
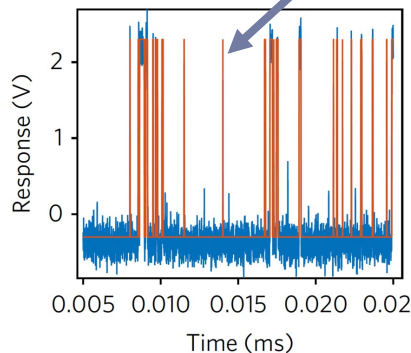
# Optical Loading & Photon Counting

Echternach et al, Nature Astronomy, 2017

## 1.5 THz FIR illumination setup



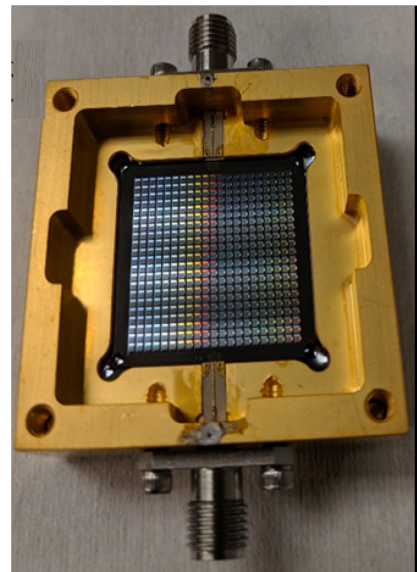
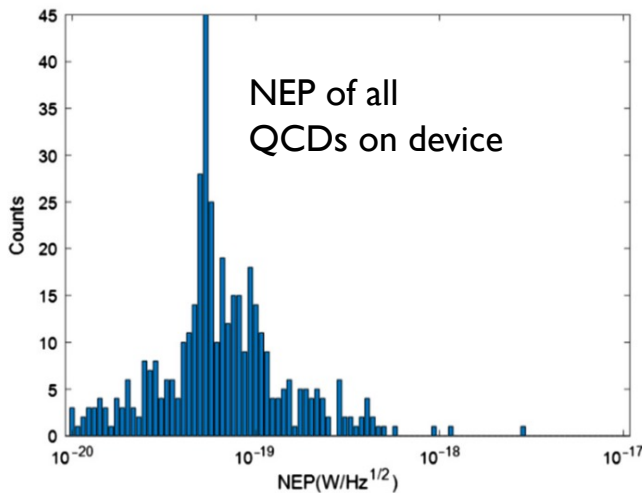
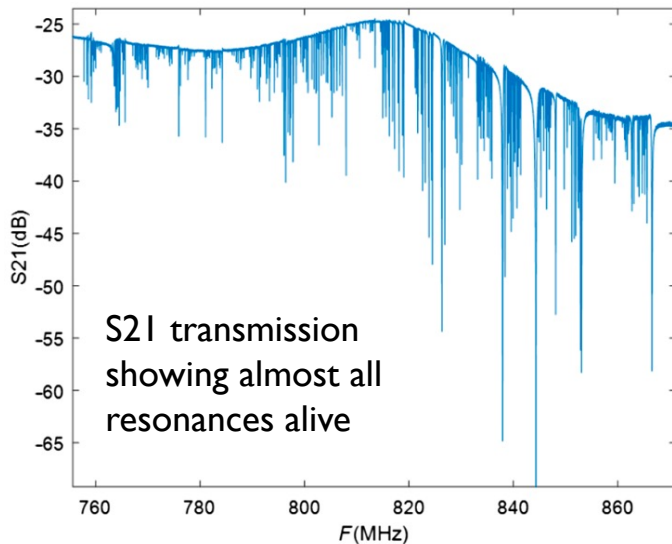
## Tunneling trace of QP events



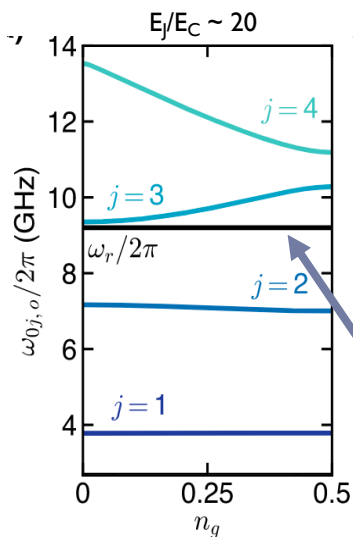
Gate charge drift + high background rate  $\rightarrow$  sweep gate voltage. Photon events changes trace = 1 count

# Semi-Latest Designs

- $^{44}\text{I}$  QCDs on a single array
- Al junctions and absorber, Niobium resonator
- $1.5\text{ }\mu\text{m}^3$  absorber volumes,  $100\times 100\text{ nm}^2$  junction dimensions



# Offset Charge Sensitive



Serniak et al, 2019

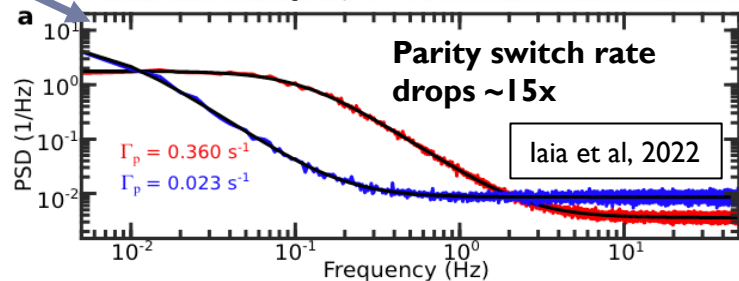
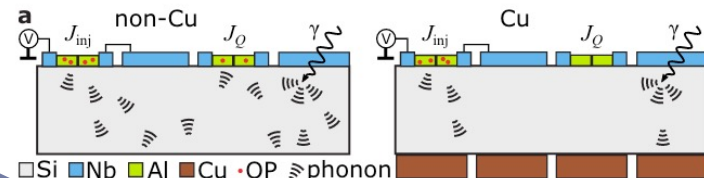
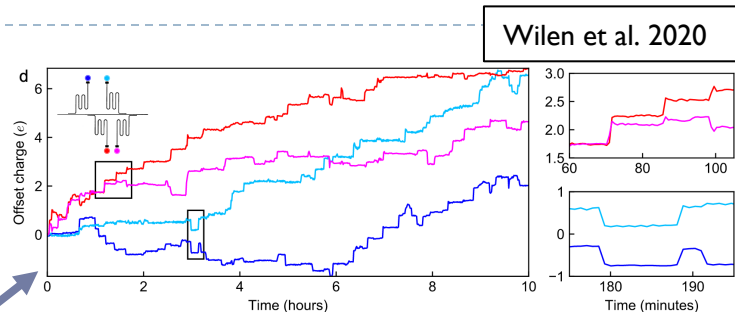
$$\chi_{i,p} = g^2 \sum_{j \neq i} \frac{2\omega_{ij,p} |\langle j,p | \hat{n} | i,p \rangle|^2}{\omega_{ij,p}^2 - \omega_r^2}$$

- QIS qubits suffer from decoherence, traced to *environmentally caused non-equilibrium quasiparticle population*

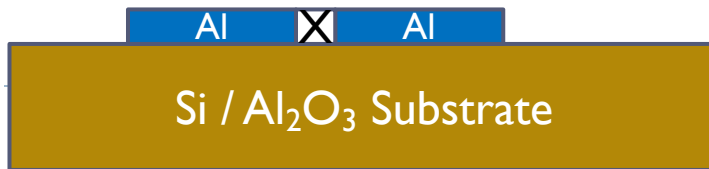
- Offset Charge Sensitive** protocols designed to study these

- Few key takeaways from QIS literature:

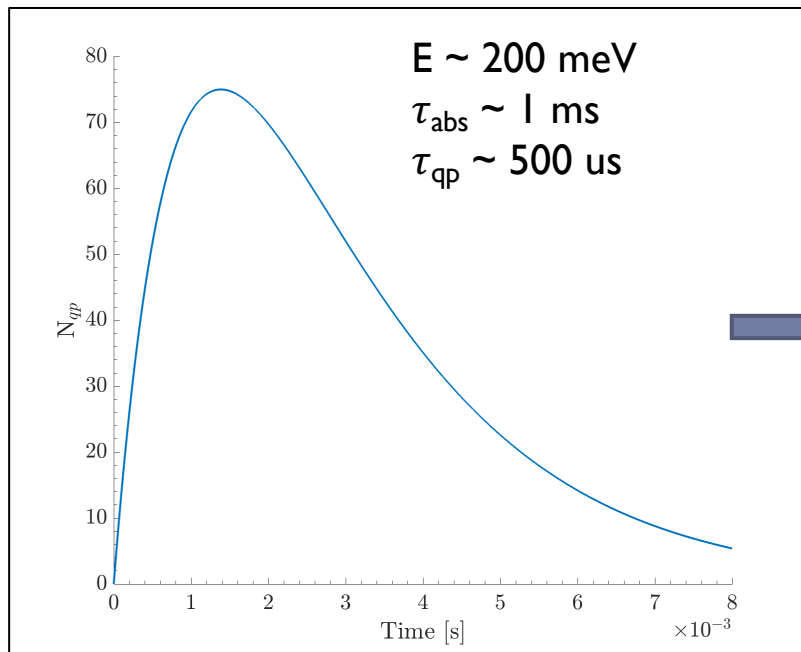
1. Already sensitive to phonon backgrounds and correlated offset charge events
2. Attempts to suppress these with absorbers
3. Can measure quasiparticle tunneling rate even in Transmon regime by dispersive shift. Lamb shift of resonator strongly disperses near bare readout frequency  $\rightarrow$  O(MHz) shift



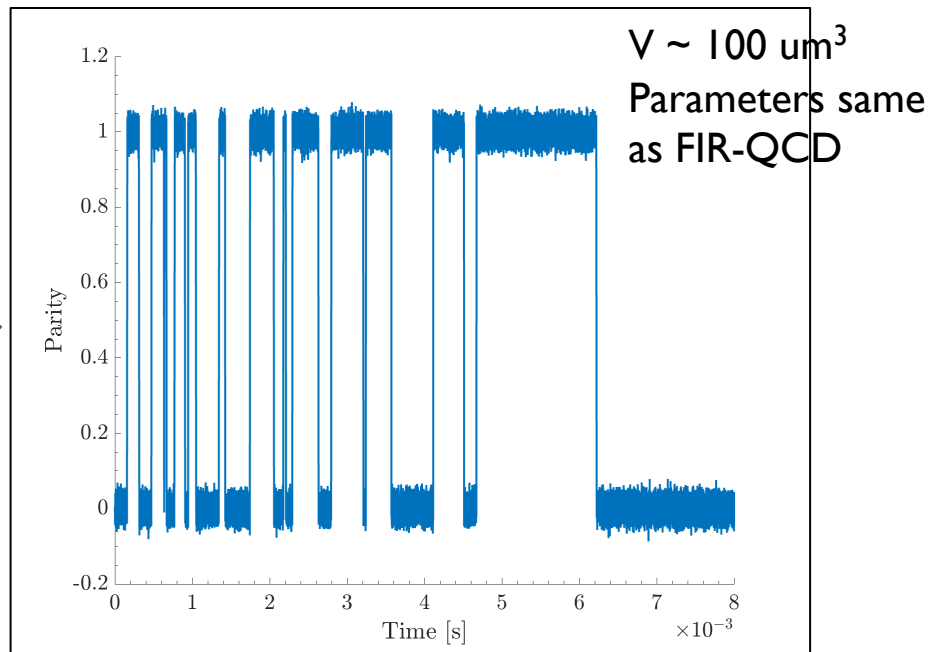
# Dark Matter QCDs



## Quasiparticle production in absorber



## Parity signal observed



# Design Considerations and Challenges

## Surface Fill Fraction

To completely absorb energy in phonon

$$f_{\text{abs}} \cdot N_{\text{surf}} \cdot f_{\text{surf}} \sim 1$$

(abs probability x num bounces x surface fill)

$$N_{\text{surf}} \sim 10^{3-5} \quad f_{\text{abs}} \sim 10^{-2} \rightarrow f_{\text{surf}} \sim 0.01\% - 10\%$$

## Readout scheme

- Sweeping gate voltage
- Measurement bandwidth
- Resonator design

## Absorber Volume

- Tunneling rate  $\leftrightarrow$  volume
- Saturation effects
- $K \sim 10 \text{ kHz } \mu\text{m}^3$
- $1 \rightarrow 10000 \text{ } \mu\text{m}^3$  absorber means  $R \sim 1 \text{ Hz}$  which is not observable

## Phonon-Film Coupling

- Coupling of energy from substrate to film  $\eta \sim 0.1 - 0.34$  from different experiments
- QP breaking film thickness dependent (30-100 nm)
- Phonon absorption lifetime  $\tau_{\text{abs}} \sim 1 \text{ ms} - 1 \text{ s}?$

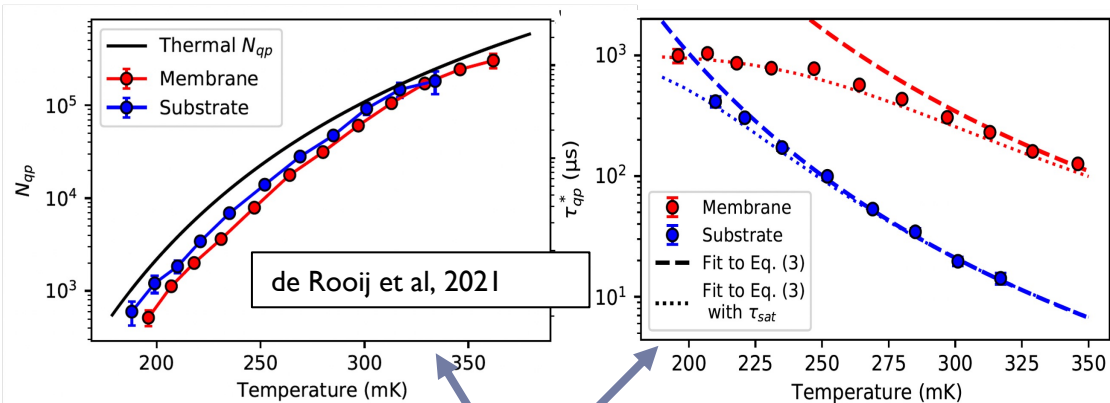
## Tunnel Junction Properties

- Barrier resistance  $R_N$  below  $\sim 5 \text{ k}\Omega$  unstable junctions?
- Fab. yield 70-90% depending on geometry
- Increase junction size but  $E_C$  plays a role in sensitivity  $\rightarrow$  Transmon readout?

## Offset Charge Drift

- Gate charge drifts on  $O(10)$ s
- Currently experiments stabilize drift by using individual bias lines  $\rightarrow$  lots of complexity for many QCDs

# Non-equilibrium quasiparticles



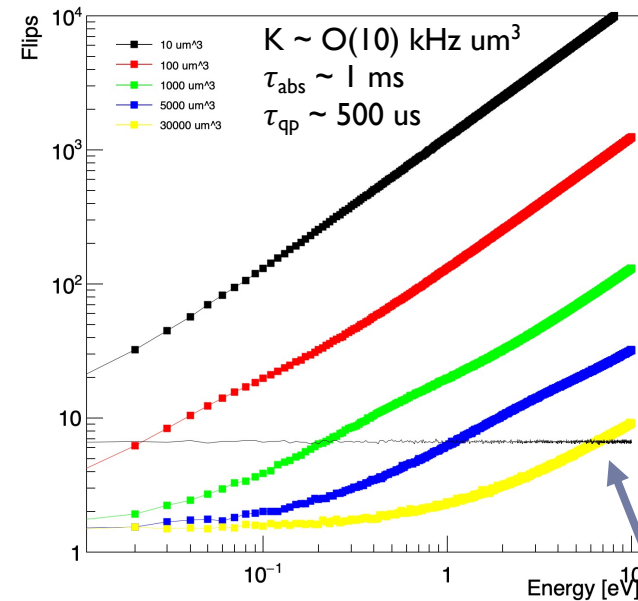
KID Generation-Recombination noise derived quasiparticle population follows thermal profile, but lifetime saturates!

If true ramifications for QCDs because these trapped QPs will not tunnel into the SCB island, and thus not contribute to the background rate.

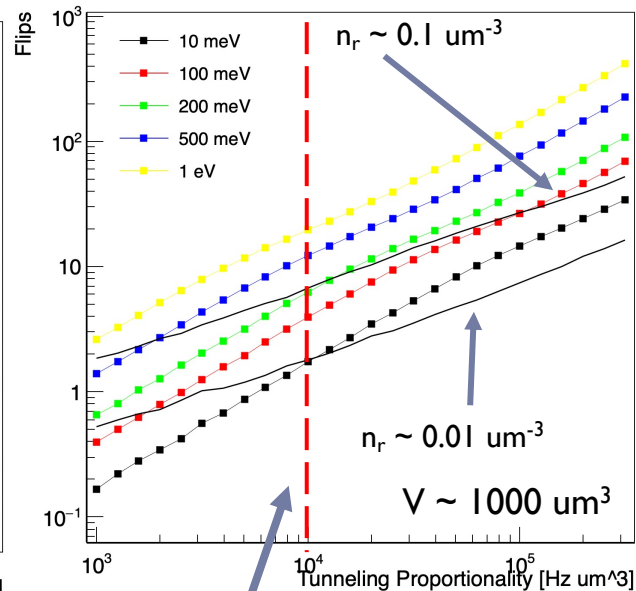
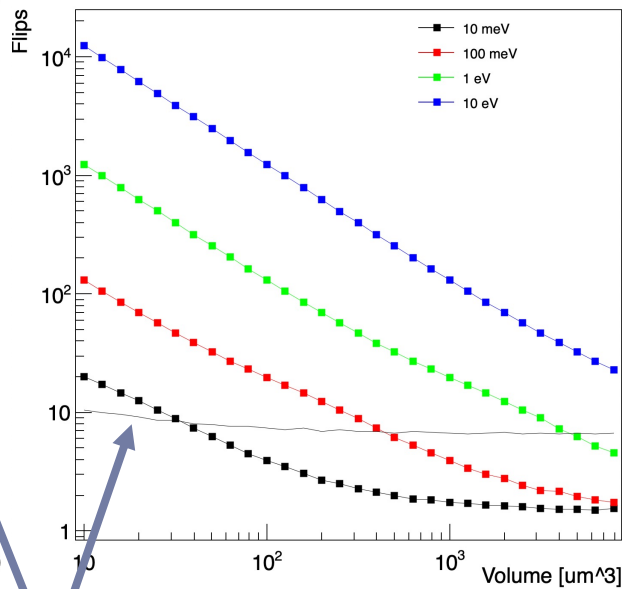
- Large uncertainty in non-equilibrium quasiparticle population.
- KID measured densities  $10\text{-}1000\text{ }\mu\text{m}^{-3}$  and lifetime measurements  $100\text{ }\mu\text{s} - 1\text{ ms}$
- Background tunneling rates in QCD and OCS measurements range from few Hz  $\rightarrow$  few kHz
- Lower values consistent with  $O(10^{-1}\text{-}10^{-2})\text{ }\mu\text{m}^{-3}$
- Residual QP density may consist of ‘trapped’ quasiparticles that limit lifetime, but such trapped QPs do not contribute noise because population does not fluctuate.

**thermal vs. trapped vs. residual**

# Expected Sensitivity & Resolution



3 $\sigma$  threshold, assuming  
background qp density 0.1  $\mu\text{m}^{-3}$   
and linear tunneling rate scaling



Current tunneling proportionality

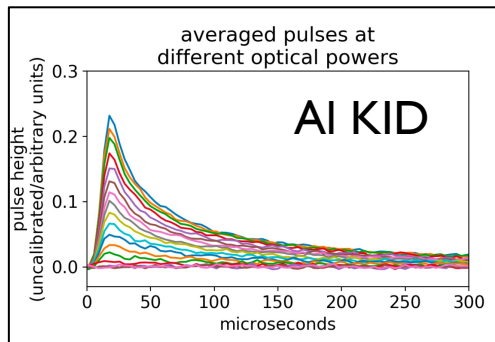


# First Device & Roadmap

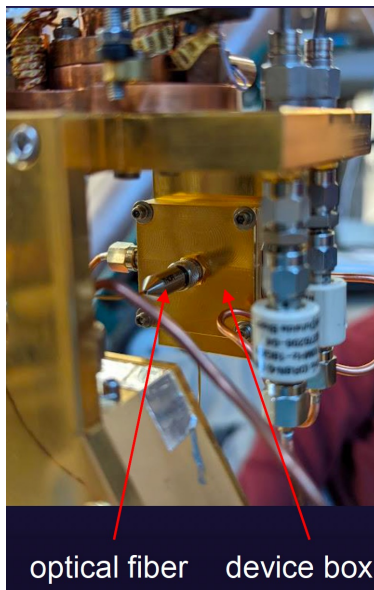
Design Stage	Details	To be studied
<b>Device A 2023 Spring</b>	<ul style="list-style-type: none"> <li>• 2 x 2 cm x 500 um Si substrate</li> <li>• 4 QCDs + 1 Al KID, 50 nm thick</li> <li>• Volume 1, 100, 1000, 10000 um<sup>3</sup> <ul style="list-style-type: none"> <li>• Direct copy of FIR QCDs</li> <li>• Latter matching KID</li> </ul> </li> </ul>	<ul style="list-style-type: none"> <li>• <b>Background &amp; tunneling rate scaling</b></li> <li>• <b>Energy resolution</b></li> <li>• <b>Referencing device performance vs KID</b></li> </ul>
<b>Device B 2023 Fall</b>	<ul style="list-style-type: none"> <li>• 2 x 2 cm x 500 um Si substrate</li> <li>• 3 QCDs</li> <li>• Varying junction sizing</li> </ul>	<ul style="list-style-type: none"> <li>• <b>Junction parameter effect on above quantities</b></li> </ul>
<b>Device C, D, E, ... 2024 - 2025</b>	<ul style="list-style-type: none"> <li>• Will be informed by previous runs</li> <li>• Material, quasiparticle trapping, Transmon readout</li> <li>• Sapphire substrate – polar material</li> <li>• 10s-100s of QCDs on one array</li> </ul>	<ul style="list-style-type: none"> <li>• <b>Eventual DM run at some facility like NEXUS Fermilab?</b></li> </ul>

# Calibration Schemes

## Optical Pulses

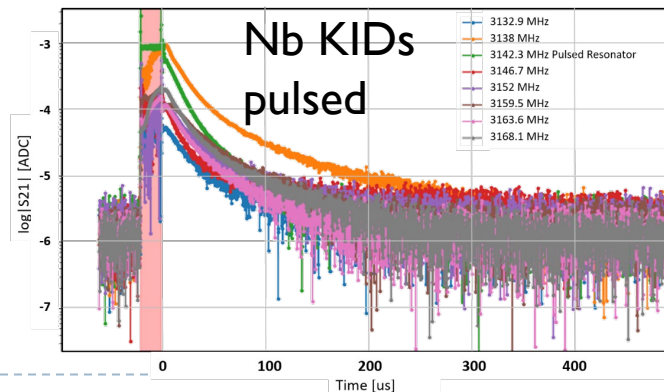


- Optical fiber into fridge to bring optical photons down to the device.
- Will infer based off the width of the distribution of amplitudes → **expect Poissonian statistics**
- Will give absolute scale on energy absorbed within substrate, **through the larger devices**



## In-situ pulsing

- Pulse on-chip resonators to generate a phonon burst → into and out of substrate
- Calibrate small absorber volumes off of response of large volume devices matched to on-chip KIDs
- Prior demonstration of scheme with KIDs



# Summary

---

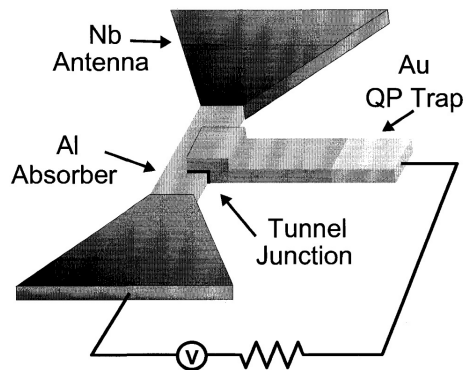
1. Single phonon sensitivity is a driving design need for low-mass particle dark matter searches
2. Quantum Capacitance Detectors & generic “Offset Charge Sensitive” schemes are one avenue to achieve this sensitivity
3. Demonstrator R&D, exploring factors in tunnel junction design, absorber volume, quasiparticle density etc. is underway

# Thanks! Questions?



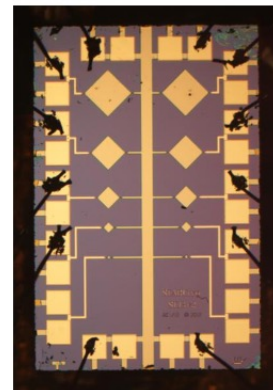
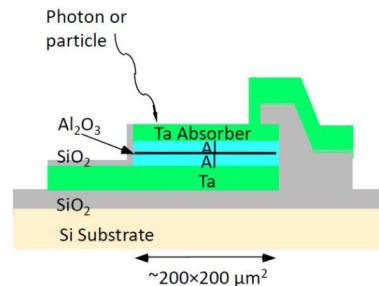
# \*STJ as photoconductors

Teufel, 2008



- Also now used for some nuclear physics applications ( $^7\text{Be}$  decay), BeEST experiment

- STJs used for >2 decades as x-ray/optical photon detectors
- Excitations in absorber tunnel across detector junction, essentially becoming a photoconductor and inducing a tunneling current  $\rightarrow$  FET pre-amp
- NEP  $10^{-19} \text{ W Hz}^{-1/2}$  reported



Leach et al 2020

No reported single quasiparticle sensitivity?